

# DATA SHEET

**74ABT00**

Quad 2-input NAND gate

Product specification

1995 Sep 18

IC23 Data Handbook

Quad 2-input NAND gate

74ABT00

QUICK REFERENCE DATA

| SYMBOL                   | PARAMETER                                    | CONDITIONS<br>$T_{amb} = 25^{\circ}\text{C}$ ;<br>GND = 0V | TYPICAL    | UNIT          |
|--------------------------|----------------------------------------------|------------------------------------------------------------|------------|---------------|
| $t_{PLH}$<br>$t_{PHL}$   | Propagation delay<br>An or Bn to $\bar{Y}_n$ | $C_L = 50\text{pF}$ ;<br>$V_{CC} = 5\text{V}$              | 2.5<br>2.0 | ns            |
| $t_{OSLH}$<br>$t_{OSHL}$ | Output to Output skew                        |                                                            | 0.4        | ns            |
| $C_{IN}$                 | Input capacitance                            | $V_I = 0\text{V}$ or $V_{CC}$                              | 3          | pF            |
| $I_{CC}$                 | Total supply current                         | Outputs disabled;<br>$V_{CC} = 5.5\text{V}$                | 50         | $\mu\text{A}$ |

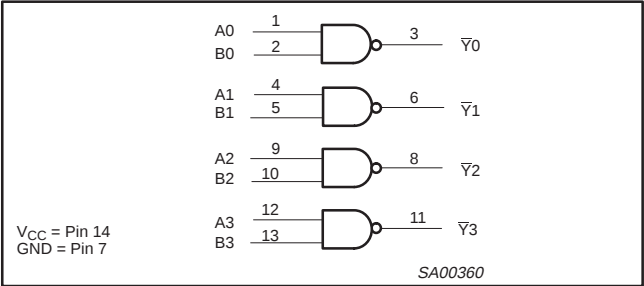
PIN CONFIGURATION



LOGIC SYMBOL



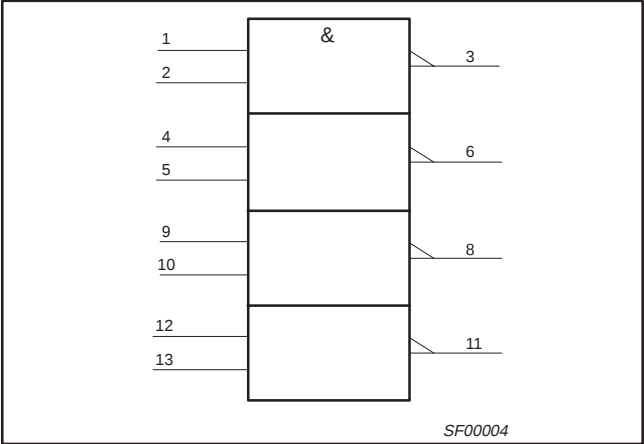
LOGIC DIAGRAM



PIN DESCRIPTION

| PIN NUMBER                | SYMBOL      | NAME AND FUNCTION       |
|---------------------------|-------------|-------------------------|
| 1, 2, 4, 5, 9, 10, 12, 13 | An-Bn       | Data inputs             |
| 3, 6, 8, 11               | $\bar{Y}_n$ | Data outputs            |
| 7                         | GND         | Ground (0V)             |
| 14                        | $V_{CC}$    | Positive supply voltage |

LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

| INPUTS |   | OUTPUT    |
|--------|---|-----------|
| A      | B | $\bar{Y}$ |
| L      | L | H         |
| L      | H | H         |
| H      | L | H         |
| H      | H | L         |

NOTES:  
H = High voltage level  
L = Low voltage level

ORDERING INFORMATION

| PACKAGES                    | TEMPERATURE RANGE | OUTSIDE NORTH AMERICA | NORTH AMERICA | DWG NUMBER |
|-----------------------------|-------------------|-----------------------|---------------|------------|
| 14-Pin Plastic DIP          | -40°C to +85°C    | 74ABT00 N             | 74ABT00 N     | SOT27-1    |
| 14-Pin plastic SO           | -40°C to +85°C    | 74ABT00 D             | 74ABT00 D     | SOT108-1   |
| 14-Pin Plastic SSOP Type II | -40°C to +85°C    | 74ABT00 DB            | 74ABT00 DB    | SOT337-1   |
| 14-Pin Plastic TSSOP Type I | -40°C to +85°C    | 74ABT00 PW            | 74ABT00PW DH  | SOT402-1   |

## Quad 2-input NAND gate

74ABT00

ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>

| SYMBOL    | PARAMETER                      | CONDITIONS                  | RATING       | UNIT |
|-----------|--------------------------------|-----------------------------|--------------|------|
| $V_{CC}$  | DC supply voltage              |                             | −0.5 to +7.0 | V    |
| $I_{IK}$  | DC input diode current         | $V_I < 0$                   | −18          | mA   |
| $V_I$     | DC input voltage <sup>3</sup>  |                             | −1.2 to +7.0 | V    |
| $I_{OK}$  | DC output diode current        | $V_O < 0$                   | −50          | mA   |
| $V_{OUT}$ | DC output voltage <sup>3</sup> | output in Off or High state | −0.5 to +5.5 | V    |
| $I_{OUT}$ | DC output current              | output in Low state         | 40           | mA   |
| $T_{stg}$ | Storage temperature range      |                             | −65 to 150   | °C   |

## NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## RECOMMENDED OPERATING CONDITIONS

| SYMBOL              | PARAMETER                            | LIMITS |          | UNIT |
|---------------------|--------------------------------------|--------|----------|------|
|                     |                                      | MIN    | MAX      |      |
| $V_{CC}$            | DC supply voltage                    | 4.5    | 5.5      | V    |
| $V_I$               | Input voltage                        | 0      | $V_{CC}$ | V    |
| $V_{IH}$            | High-level input voltage             | 2.0    |          | V    |
| $V_{IL}$            | Low-level input voltage              |        | 0.8      | V    |
| $I_{OH}$            | High-level output current            |        | −15      | mA   |
| $I_{OL}$            | Low-level output current             |        | 20       | mA   |
| $\Delta t/\Delta v$ | Input transition rise or fall rate   | 0      | 5        | ns/V |
| $T_{amb}$           | Operating free-air temperature range | −40    | +85      | °C   |

## DC ELECTRICAL CHARACTERISTICS

| SYMBOL           | PARAMETER                                            | TEST CONDITIONS                                                                                      | LIMITS                   |       |      |                                      |      | UNIT |
|------------------|------------------------------------------------------|------------------------------------------------------------------------------------------------------|--------------------------|-------|------|--------------------------------------|------|------|
|                  |                                                      |                                                                                                      | T <sub>amb</sub> = +25°C |       |      | T <sub>amb</sub> = −40°C<br>to +85°C |      |      |
|                  |                                                      |                                                                                                      | MIN                      | TYP   | MAX  | MIN                                  | MAX  |      |
| V <sub>IK</sub>  | Input clamp voltage                                  | V <sub>CC</sub> = 4.5V; I <sub>IK</sub> = −18mA                                                      |                          | −0.9  | −1.2 |                                      | −1.2 | V    |
| V <sub>OH</sub>  | High-level output voltage                            | V <sub>CC</sub> = 4.5V; I <sub>OH</sub> = −15mA; V <sub>I</sub> = V <sub>IL</sub> or V <sub>IH</sub> | 2.5                      | 2.9   |      | 2.5                                  |      | V    |
| V <sub>OL</sub>  | Low-level output voltage                             | V <sub>CC</sub> = 4.5V; I <sub>OL</sub> = 20mA; V <sub>I</sub> = V <sub>IL</sub> or V <sub>IH</sub>  |                          | 0.35  | 0.5  |                                      | 0.5  | V    |
| I <sub>I</sub>   | Input leakage current                                | V <sub>CC</sub> = 5.5V; V <sub>I</sub> = GND or 5.5V                                                 |                          | ±0.01 | ±1.0 |                                      | ±1.0 | μA   |
| I <sub>OFF</sub> | Power-off leakage current                            | V <sub>CC</sub> = 0.0V; V <sub>O</sub> or V <sub>I</sub> ≤ 4.5V                                      |                          | ±5.0  | ±100 |                                      | ±100 | μA   |
| I <sub>CEX</sub> | Output High leakage current                          | V <sub>CC</sub> = 5.5V; V <sub>O</sub> = 5.5V; V <sub>I</sub> = GND or V <sub>CC</sub>               |                          | 5.0   | 50   |                                      | 50   | μA   |
| I <sub>O</sub>   | Output current <sup>1</sup>                          | V <sub>CC</sub> = 5.5V; V <sub>O</sub> = 2.5V                                                        | −50                      | −75   | −180 | −50                                  | −180 | mA   |
| I <sub>CC</sub>  | Quiescent supply current                             | V <sub>CC</sub> = 5.5V; V <sub>I</sub> = GND or V <sub>CC</sub>                                      |                          | 2     | 50   |                                      | 50   | μA   |
| ΔI <sub>CC</sub> | Additional supply current per input pin <sup>2</sup> | V <sub>CC</sub> = 5.5V; One data input at 3.4V, other inputs at V <sub>CC</sub> or GND               |                          | 0.25  | 500  |                                      | 500  | μA   |

## NOTES:

- Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
- This is the increase in supply current for each input at 3.4V.

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74ABT00

AC CHARACTERISTICS

GND = 0V;  $t_R = t_F = 2.5\text{ns}$ ;  $C_L = 50\text{pF}$ ,  $R_L = 500\Omega$

| SYMBOL                                              | PARAMETER                                        | WAVEFORM | LIMITS                                              |            |            |                                                                    |            | UNIT |
|-----------------------------------------------------|--------------------------------------------------|----------|-----------------------------------------------------|------------|------------|--------------------------------------------------------------------|------------|------|
|                                                     |                                                  |          | T <sub>amb</sub> = +25°C<br>V <sub>CC</sub> = +5.0V |            |            | T <sub>amb</sub> = −40°C to +85°C<br>V <sub>CC</sub> = +5.0V ±0.5V |            |      |
|                                                     |                                                  |          | MIN                                                 | TYP        | MAX        | MIN                                                                | MAX        |      |
| t <sub>PLH</sub><br>t <sub>PHL</sub>                | Propagation delay<br>An or Bn to $\bar{Y}_n$     | 1        | 1.0<br>1.0                                          | 2.5<br>2.0 | 3.6<br>2.8 | 1.0<br>1.0                                                         | 4.1<br>3.4 | ns   |
| t <sub>OSHL</sub><br>t <sub>OSLH</sub> <sup>1</sup> | Output to Output skew<br>An or Bn to $\bar{Y}_n$ | 2        |                                                     | 0.4<br>0.4 | 0.5<br>0.5 |                                                                    | 0.5<br>0.5 | ns   |

**NOTE:**  
1. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the the same direction, either HIGH-to-LOW ( $t_{\text{OSHL}}$ ) or LOW-to-HIGH ( $t_{\text{OSLH}}$ ); parameter guaranteed by design.

AC WAVEFORMS

$V_M = 1.5\text{V}$ ,  $V_{\text{IN}} = \text{GND to } 3.0\text{V}$



Waveform 1. Propagation delay for inverting outputs



Waveform 2. Common edge skew

TEST CIRCUIT AND WAVEFORMS

Test Circuit for Outputs

Input Pulse Definition

**DEFINITIONS**

$R_L$  = Load resistor; see AC CHARACTERISTICS for value.

$C_L$  = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

$R_T$  = Termination resistance should be equal to  $Z_{\text{OUT}}$  of pulse generators.

| FAMILY | INPUT PULSE REQUIREMENTS |           |       |       |       |
|--------|--------------------------|-----------|-------|-------|-------|
|        | Amplitude                | Rep. Rate | $t_W$ | $t_R$ | $t_F$ |
| 74ABT  | 3.0V                     | 1MHz      | 500ns | 2.5ns | 2.5ns |

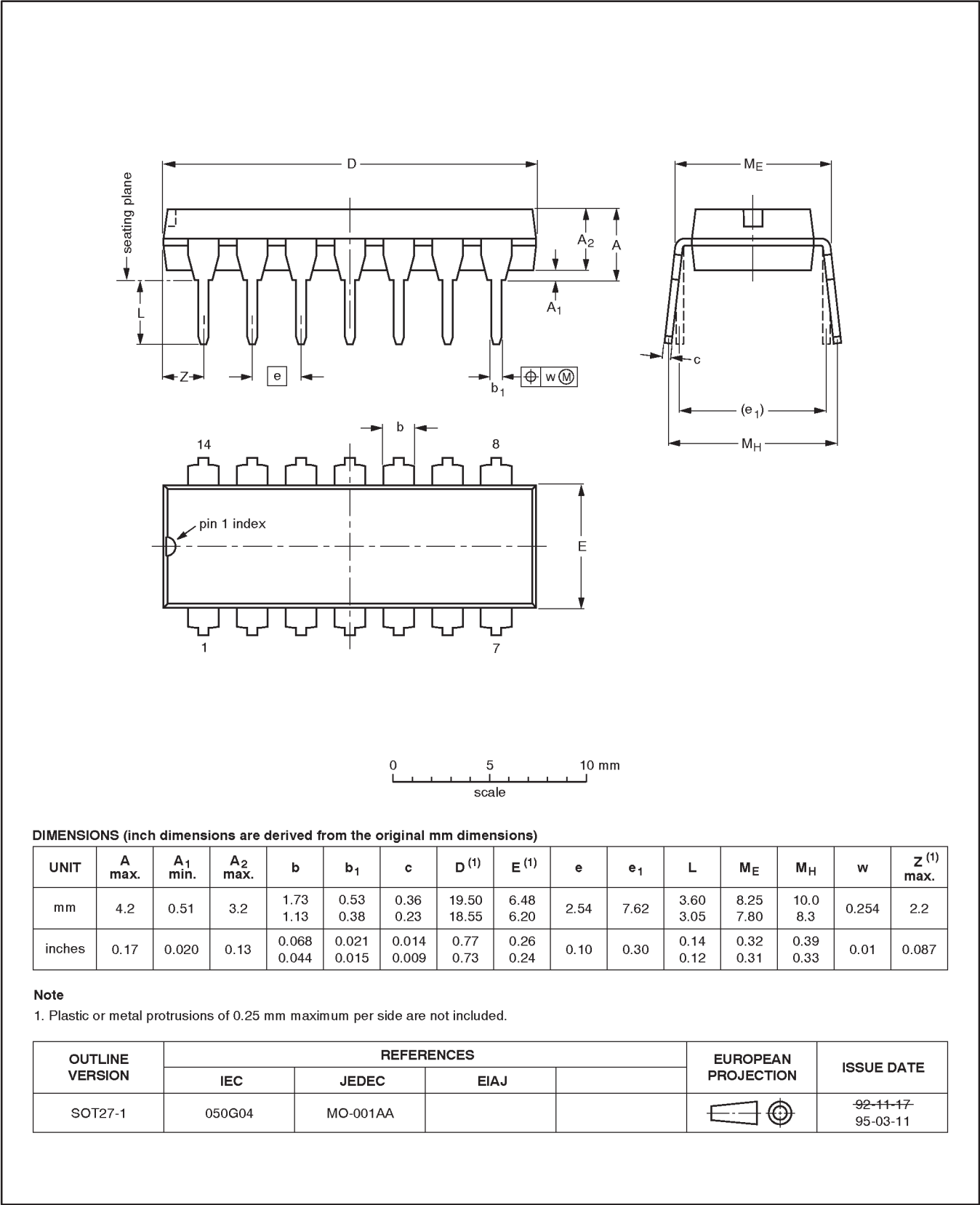
SH00067

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DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



Quad 2-input NAND gate

74ABT00

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



Quad 2-input NAND gate

74ABT00

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



Quad 2-input NAND gate

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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



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**NOTES**

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| DEFINITIONS               |                        |                                                                                                                                                                                                                                                            |
|---------------------------|------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Data Sheet Identification | Product Status         | Definition                                                                                                                                                                                                                                                 |
| Objective Specification   | Formative or in Design | This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.                                                                                                         |
| Preliminary Specification | Preproduction Product  | This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product. |
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- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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